

BB207

FM variable capacitance double diode

Rev. 02 — 27 April 2004

Product data sheet



1.1 General description

The BB207 is a variable capacitance double diode with a common cathode, fabricated in silicon planar technology, and encapsulated in the SOT23 small plastic SMD package.

1.2 Features

- Excellent linearity
- C_{d(1V)}: 81 pF; C_{d(7.5V)}: 27.6 pF
- $ightharpoonup C_{d(1V)}$ to $C_{d(7.5V)}$ ratio: min. 2.6
- Very low series resistance
- Small plastic SMD package.

1.3 Applications

Electronic tuning in FM-radio.

2. Pinning information

Table 1: Discrete pinning

Pin	Description	Simplified outline	Symbol
1	anode 1		_
2	anode 2		3
3	common cathode	1 2 Top view	$1 \frac{1}{\sqrt{1+\frac{1}{2}}} 2$ $sym032$

3. Ordering information

Table 2: Ordering information

Type number	Package		
	Name	Description	Version
BB207	-	plastic surface mounted package; 3 leads	SOT23



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Marking

Table 3: Marking

Type number	Marking code [1]
BB207	*13

^{[1] * =} p: made in Hong Kong. * = w: made in China.

Limiting values 5.

Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_R	continuous reverse voltage		-	15	V
l _F	continuous forward current		-	20	mA
T _{stg}	storage temperature		-55	+150	°C
Tj	junction temperature		– 55	+125	°C

Characteristics 6.

Electrical Characteristics

 $T_i = 25 \,^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _R	reverse current	V _R = 15 V; see <u>Figure 2</u>	-	_	10	nA
		V _R = 15 V; T _j = 85 °C; see <u>Figure 2</u>	-	_	200	nA
r _s	diode series resistance	f = 100 MHz; V _R = 3 V	_	0.2	0.4	Ω
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; see Figure 1	76	81	86	pF
		V _R = 3 V; f = 1 MHz; see Figure 1	_	50.5	_	pF
		V _R = 7.5 V; f = 1 MHz; see <u>Figure 1</u>	25.5	27.6	29.7	pF
		V _R = 8 V; f = 1 MHz; see Figure 1	_	26.3	_	pF
$\frac{C_{d(1V)}}{C_{d(7.5V)}}$	capacitance ratio	f = 1 MHz	2.6	-	3.3	

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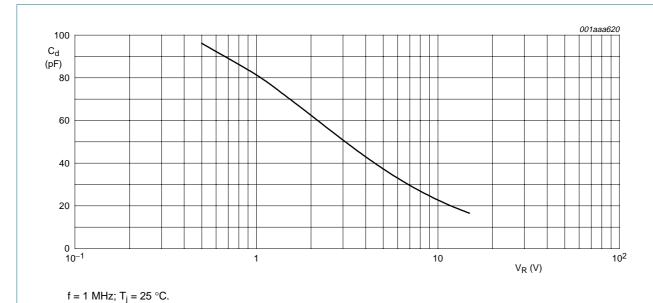


Fig 1. Diode capacitance as a function of reverse voltage; typical values.

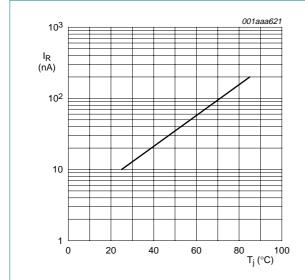


Fig 2. Reverse current as a function of junction temperature; maximum values.

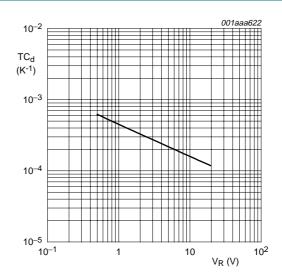
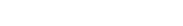


Fig 3. Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.



Package outline

Plastic surface mounted package; 3 leads

SOT23

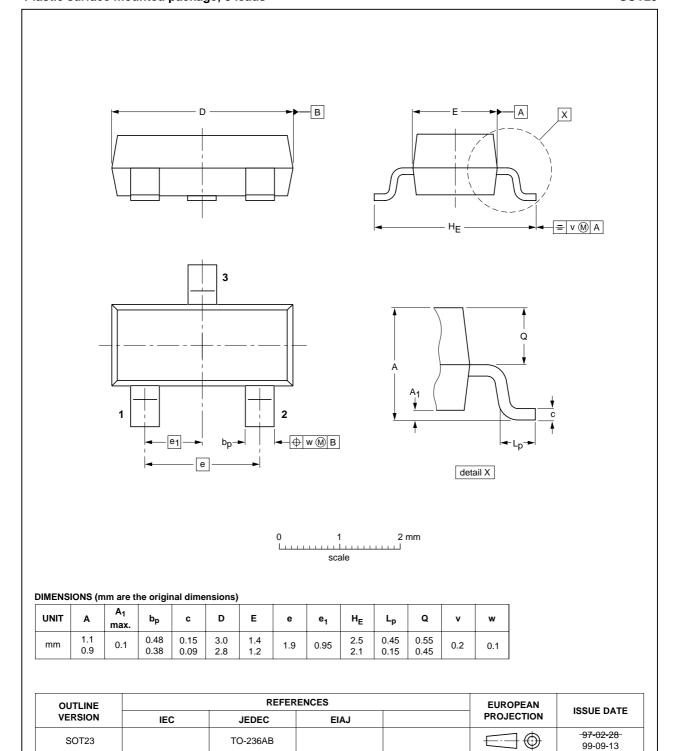


Fig 4. Package outline.

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Table 6: Revision history

Document ID	Release date	Data sheet status	Change notice	Order number	Supersedes
BB207_2	20040427	Product data	-	9397 750 13003	BB207_N_1
Modifications:		at of this data sheet has on standard of Philips S	•	o comply with the n	ew presentation and
BB207_N_1	20031117	Preliminary data	-	9397 750 12695	-

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9. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
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